NSN 5961-01-097-5530

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-097-5530 **Inclosure Material:** Metal **Overall Length:** Between 0.060 inches and 0.085 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** -70.0 collector to base voltage, dc and -60.0 collector to emitter voltage, dc and -6.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 1.2 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 99974-7892302 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No